



PJU12P06 / PJD12P06

60V P-Channel Enhancement Mode MOSFET

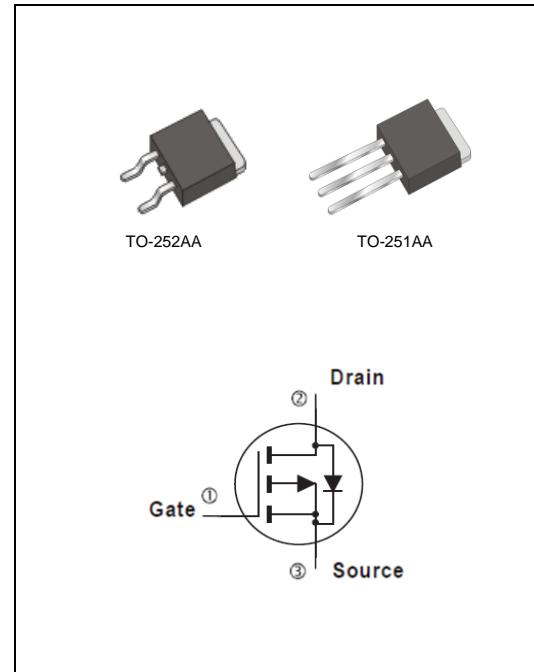
Voltage -60 V Current -12 A

Features

- $R_{DS(ON)}$, $V_{GS} @ -10V$, $I_D @ -6A < 155m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-251AA ,TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNITS |
|---|---------------------|-----------------|-------|
| Drain-Source Voltage | V_{DS} | -60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | |
| Continuous Drain Current $T_C=25^\circ C$ | I_D | -12 | A |
| $T_C=100^\circ C$ | I_D | -7.7 | |
| Pulsed Drain Current ^(Note 1) | I_{DM} | -48 | |
| Power Dissipation $T_C=25^\circ C$ | P_D | 50 | W |
| $T_C=100^\circ C$ | P_D | 20 | |
| Continuous Drain Current $T_A=25^\circ C$ | I_D | -2.6 | A |
| $T_A=70^\circ C$ | I_D | -2.0 | |
| Power Dissipation $T_A=25^\circ C$ | P_D | 2.0 | W |
| Power Dissipation $T_A=70^\circ C$ | P_D | 1.3 | |
| Single Pulse Avalanche Energy ^(Note 6) | E_{AS} | 337 | mJ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55~150 | °C |
| Typical Thermal Resistance ^(Note 4,5) | Junction to Case | $R_{\theta JC}$ | 2.5 |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 |

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|--------------|--|------|-------|-----------|-----------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=-250\mu A$ | -60 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | -2.0 | -2.86 | -4.0 | |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=-10V, I_D=6A$ | - | 132 | 155 | $m\Omega$ |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=-60V, V_{GS}=0V$ | - | - | -1.0 | μA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | - | - | ± 100 | nA |
| Dynamic <small>(Note 7)</small> | | | | | | |
| Total Gate Charge | Q_g | $V_{DS}=-48V, I_D=-12A,$ $V_{GS}=-10V$ <small>(Note 2,3)</small> | - | 10.9 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 2.7 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 4.0 | - | |
| Input Capacitance | C_{iss} | $V_{DS}=-25V, V_{GS}=0V,$ $f=1.0MHz$ | - | 385 | - | pF |
| Output Capacitance | C_{oss} | | - | 158 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 31 | - | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DS}=-30V, I_D=-12A,$ $V_{GS}=-10V, R_G=6\Omega$ <small>(Note 2,3)</small> | - | 4.4 | - | ns |
| Turn-On Rise Time | t_r | | - | 59 | - | |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 20 | - | |
| Turn-Off Fall Time | t_f | | - | 36 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I_s | --- | - | - | -12 | A |
| Diode Forward Voltage | V_{SD} | $I_s=-1A, V_{GS}=0V$ | - | -0.75 | -1 | V |
| Reverse Recovery Time | trr | $V_{GS}=0V, I_s=-12A$ $dI_F/dt=100A/us$ <small>(Note 2)</small> | - | 37 | - | ns |
| Reverse Recovery Charge | Qrr | | - | 67 | - | nC |

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ C$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^\circ C$.
4. The maximum current rating is package limited
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
6. $L=3mH, I_{AS}=-15A, V_{GS}=-10V, V_{DS}=-25V, R_G=25\Omega$, Starting $T_J=25^\circ C$
7. Guaranteed by design, not subject to production testing.



PJU12P06 / PJD12P06

TYPICAL CHARACTERISTIC CURVES

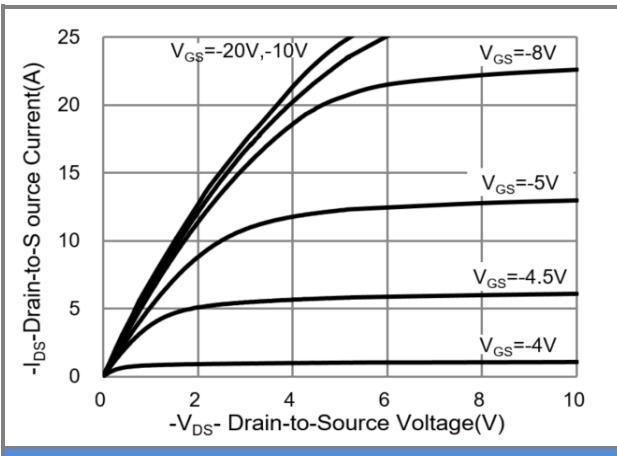


Fig.1 On-Region Characteristics

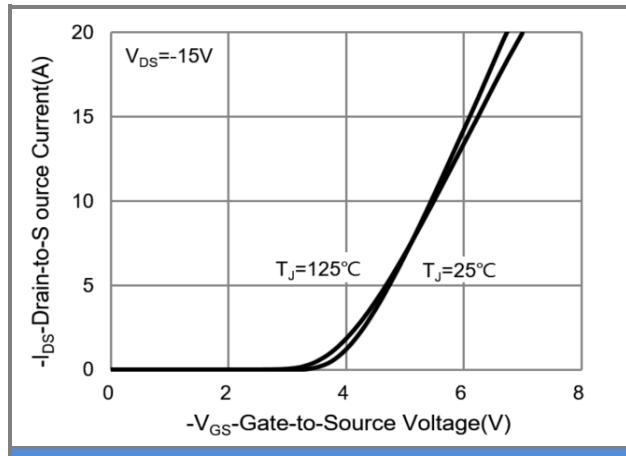


Fig.2 Transfer Characteristics

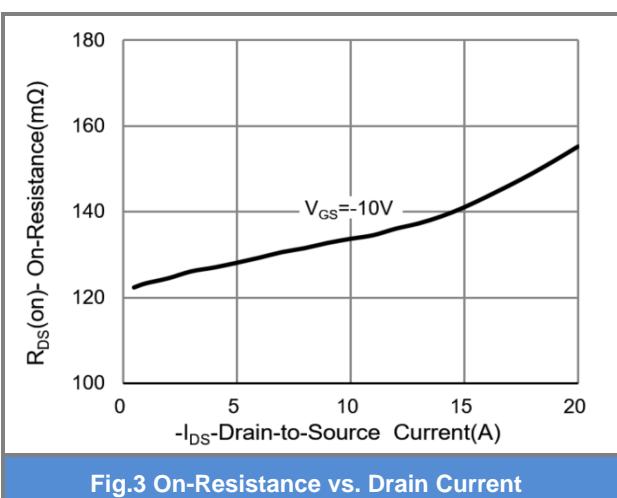


Fig.3 On-Resistance vs. Drain Current

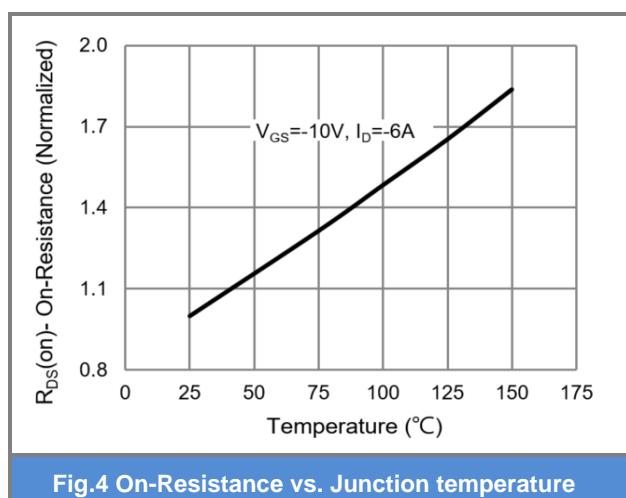


Fig.4 On-Resistance vs. Junction temperature

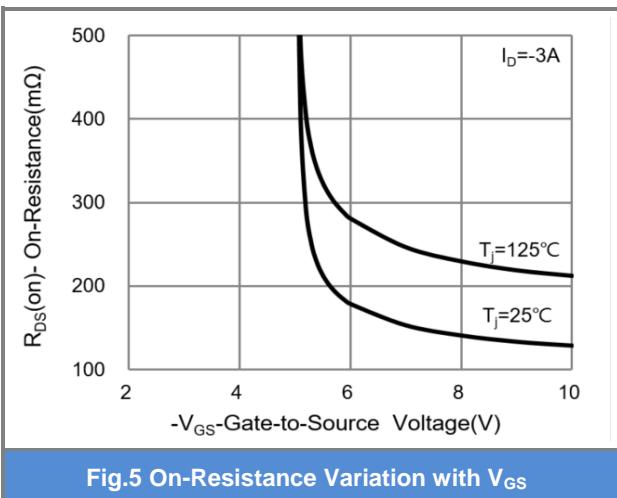


Fig.5 On-Resistance Variation with V_GS

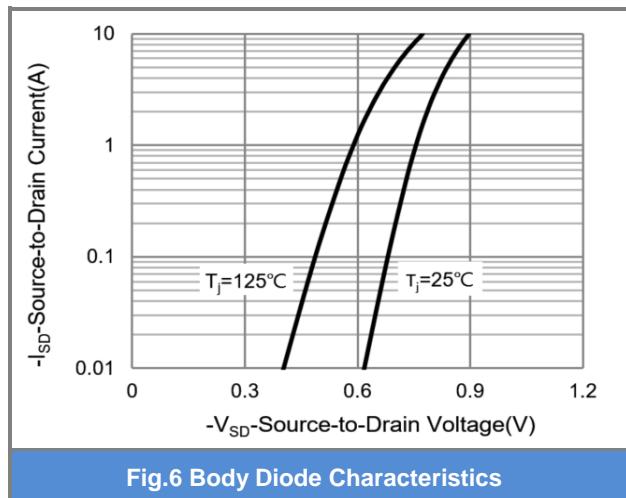


Fig.6 Body Diode Characteristics



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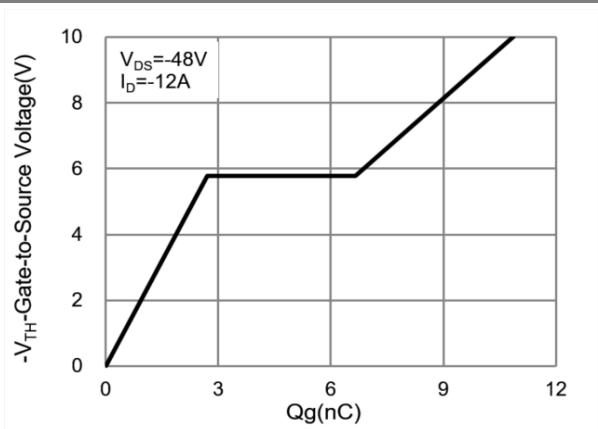


Fig.7 Gate-Charge Characteristics

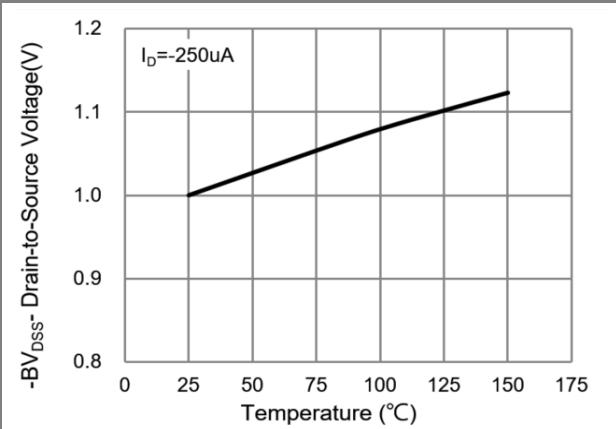


Fig.8 Breakdown Voltage Variation vs. Temperature

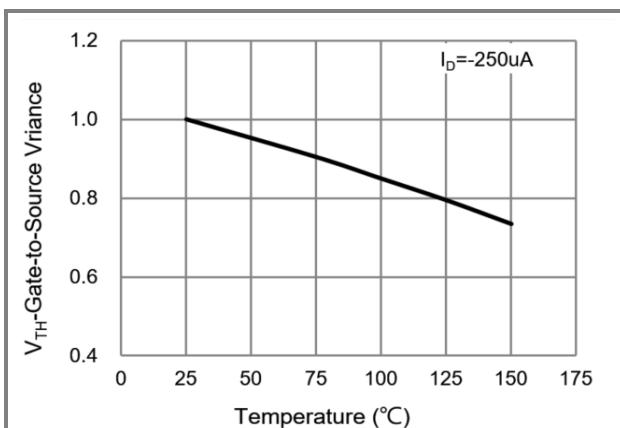


Fig.9 Threshold Voltage Variation with Temperature

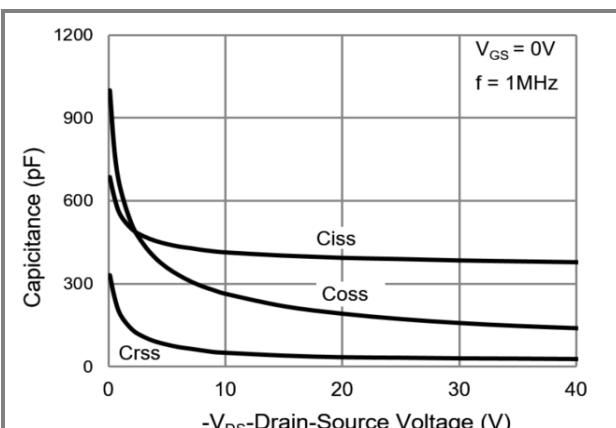


Fig.10 Capacitance vs. Drain-Source Voltage

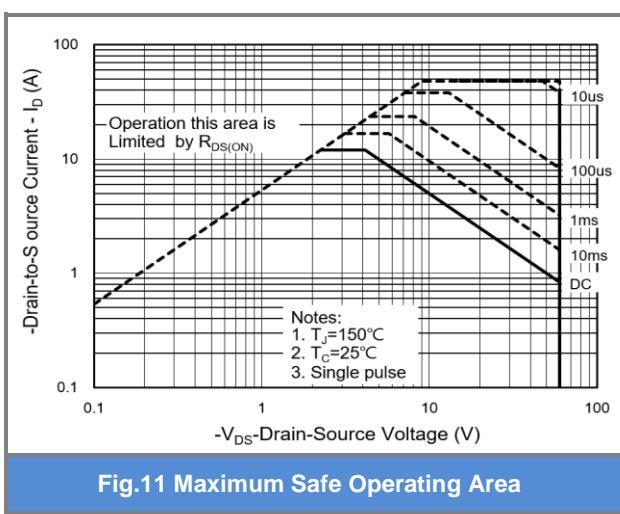


Fig.11 Maximum Safe Operating Area



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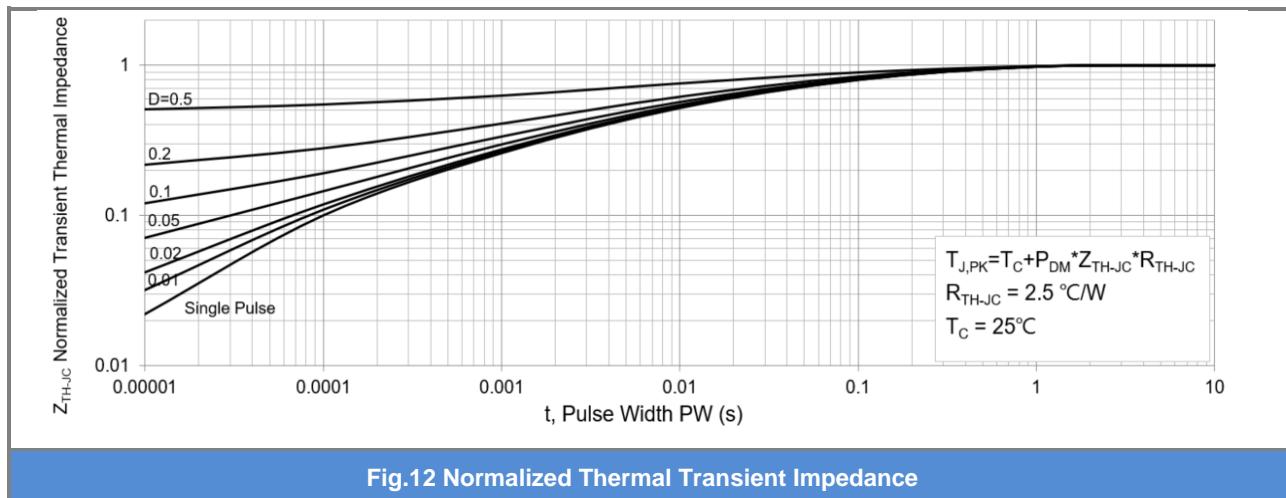
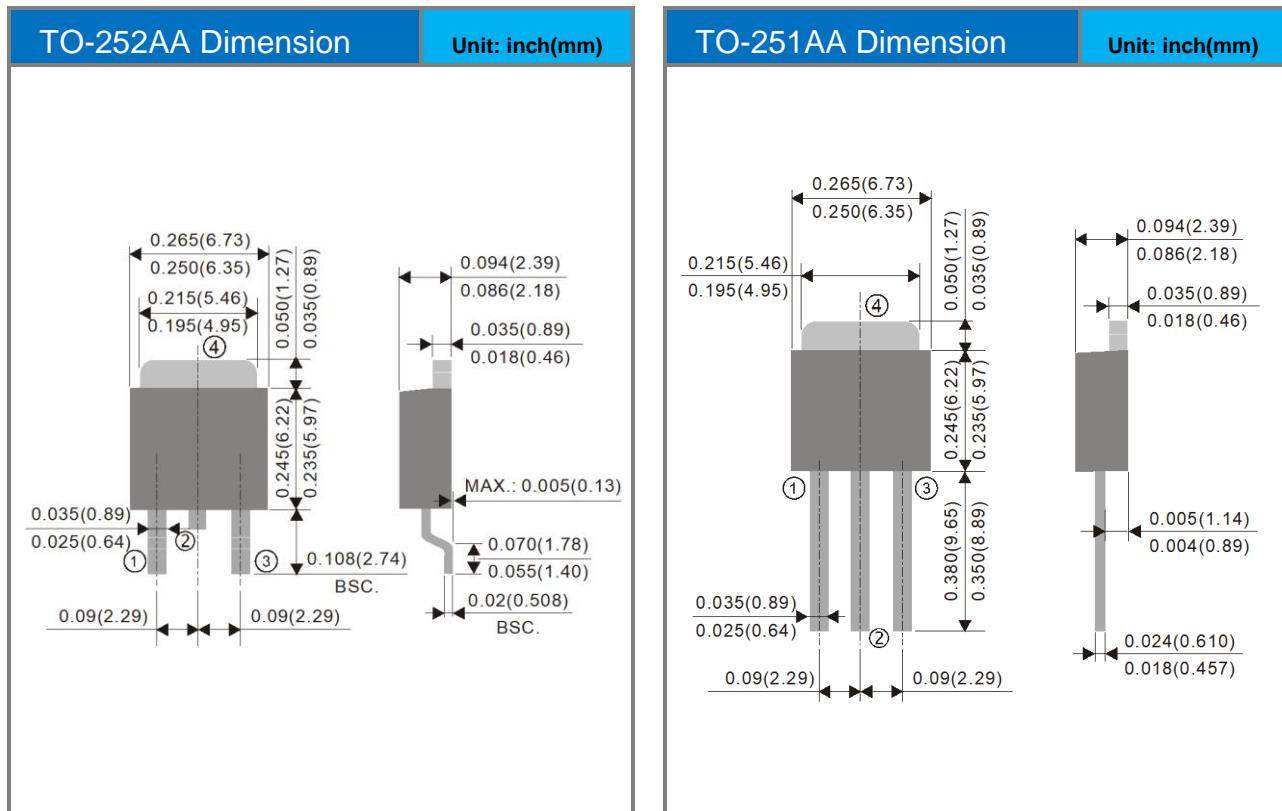


Fig.12 Normalized Thermal Transient Impedance



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Packaging Information



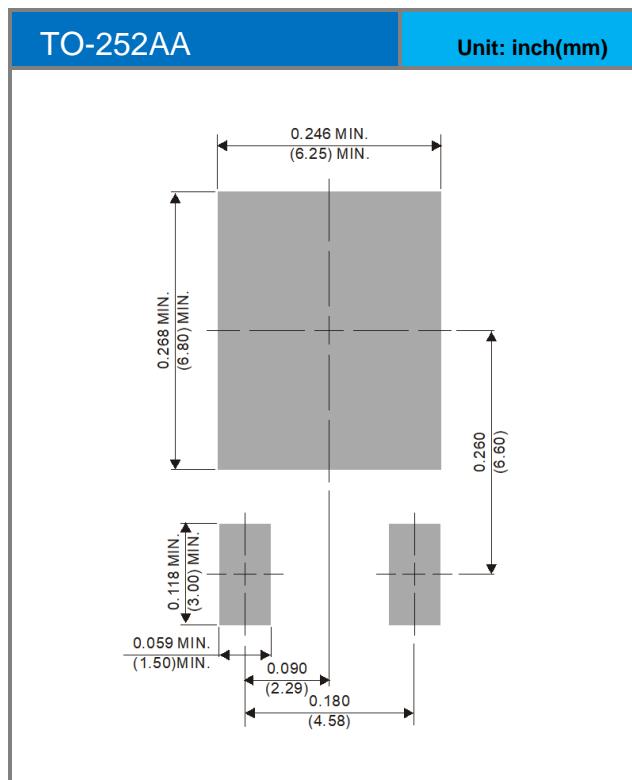


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Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version |
|----------------------|--------------|---------------------|---------|--------------|
| PJU12P06_T0_00001 | TO-251AA | 80pcs / Tube | U12P06 | Halogen free |
| PJD12P06_L2_00001 | TO-252AA | 3,000pcs / 13" reel | D12P06 | Halogen free |

Mounting Pad Layout





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